

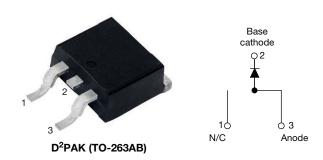
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Vishay Semiconductors

COMPLIANT HALOGEN

FREE

High Performance Schottky Rectifier, 20 A



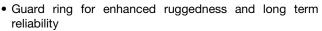
LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	20 A				
V _R	35 V, 40 V, 45 V				
V _F at I _F	0.51 V				
I _{RM} typ.	105 mA at 125 °C				
T _J max.	150 °C				
E _{AS}	27 mJ				
Package	D ² PAK (TO-263AB)				
Circuit configuration	Single				

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-20TQ... Schottky rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MECHANICAL DATA

Case: D²PAK (TO-268AB)

Molding compound meets UL 94-V0 flammability rating

Terminals: matte tin plated leads, solderable per

J-STD-002

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL CHARACTERISTICS VALUES UNITS							
I _{F(AV)}	Rectangular waveform	20	А				
V _{RRM}	Range	35 to 45	V				
I _{FSM}	$t_p = 5 \mu s sine$	1800	Α				
V _F	20 A _{pk} , T _J = 125 °C	0.51	V				
T _J	Range	-55 to +150	°C				

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-20TQ035S-M3	VS-20TQ040S-M3	VS-20TQ045S-M3	UNITS	
Maximum DC reverse voltage	V_R	35	40	45	V	
Maximum working peak reverse voltage	V_{RWM}	33	40	45	V	

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS			
Maximum average forward current See fig. 5	I _{F(AV)} 50 % duty cycle at T _C = 116 °C, rectangular waveform			20				
Maximum peak one cycle non-repetitive	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load	1800	Α			
surge current, see fig. 7		10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	400				
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 4 \text{A}, L = 3.40 \text{r}$	27	mJ				
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T_J maxim		4	Α			

Revision: 21-Dec-2021 1 Document Number: 94931



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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST COND	OITIONS	VALUES	UNITS			
		20 A	T _{.1} = 25 °C	0.57	V			
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	40 A	1j=25 C	0.73				
	VFM (1)	20 A	T 105 °C	0.51				
		40 A	T _J = 125 °C	0.67				
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	2.7	mA			
Maximum reverse leakage current	IRM \''	T _J = 125 °C	v _R = nateu v _R	150				
Typical reverse leakage current	I _{RM} ⁽¹⁾	T _J = 125 °C	V _R = Rated V _R	105	mA			
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz), 25 °C		1400	pF			
Typical series inductance	L _S	Measured lead to lead 5 mm	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs			

Note

 $^{(1)}$ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS		
Maximum junction and storag temperature range	е	T _J , T _{Stg}		-55 to 150	°C		
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	1.50	°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.50			
Approximate weight				2	g		
Approximate weight				0.07	OZ.		
Mounting torque	minimum			6 (5)	kgf · cm		
Wounting torque	maximum			12 (10)	(lbf · in)		
Marking device			Case style D ² PAK (TO-263AB)	20TC	0035S 0040S 0045S		

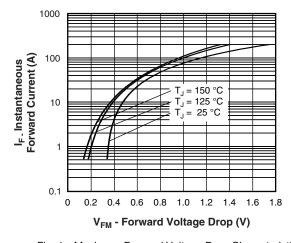


Fig. 1 - Maximum Forward Voltage Drop Characteristics

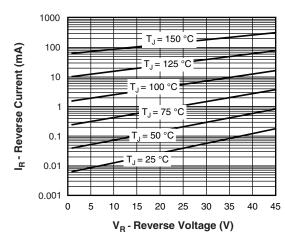


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

Revision: 21-Dec-2021 2 Document Number: 94931

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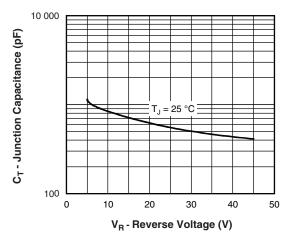


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

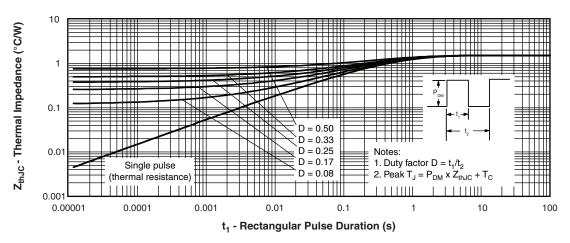


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

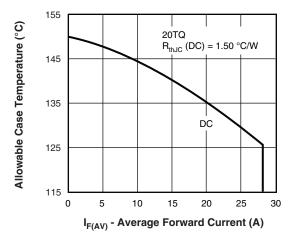


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

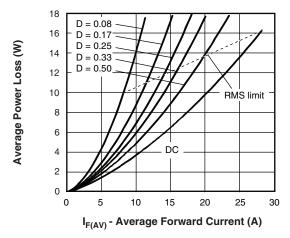
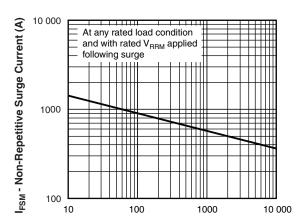


Fig. 6 - Forward Power Loss Characteristics



t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

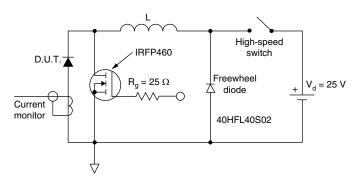
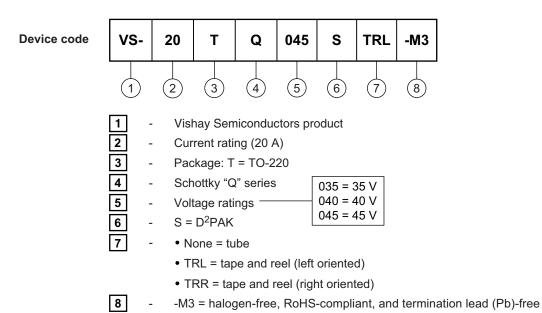


Fig. 8 - Unclamped Inductive Test Circuit

ORDERING INFORMATION TABLE



Revision: 21-Dec-2021 4 Document Number: 94931



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ORDERING INFORMATION						
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION				
VS-20TQ035S-M3	50	Antistatic plastic tubes				
VS-20TQ035STRL-M3	800	13" diameter plastic tape and reel				
VS-20TQ035STRR-M3	800	13" diameter plastic tape and reel				
VS-20TQ040S-M3	50	Antistatic plastic tubes				
VS-20TQ040STRL-M3	800	13" diameter plastic tape and reel				
VS-20TQ040STRR-M3	800	13" diameter plastic tape and reel				
VS-20TQ045S-M3	50	Antistatic plastic tubes				
VS-20TQ045STRL-M3	800	13" diameter plastic tape and reel				
VS-20TQ045STRR-M3	800	13" diameter plastic tape and reel				

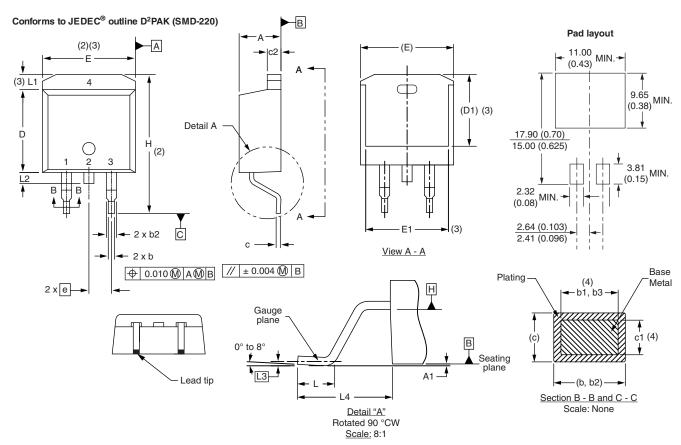
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96164				
Part marking information	www.vishay.com/doc?95444				
Packaging information	www.vishay.com/doc?96424				
SPICE model	www.vishay.com/doc?96917				



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	TERS INCHES		
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100	BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

- $^{(1)}$ Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

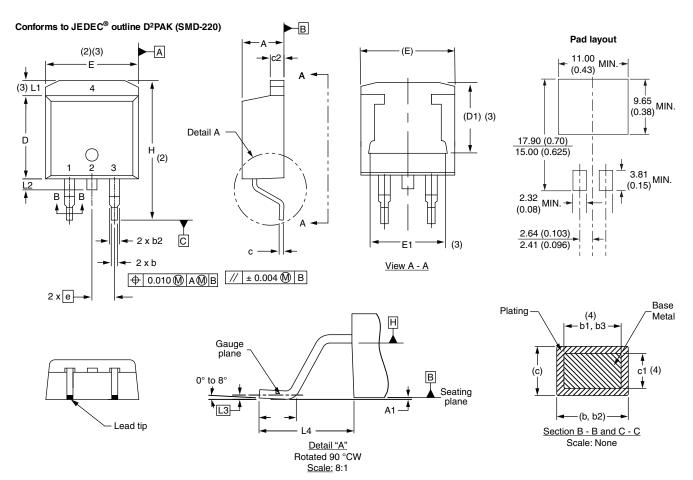
Revision: 08-Jul-15 1 Document Number: 95046



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D²PAK

DIMENSIONS in millimeters and inches



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